Seat	
No	

No.

M.Sc. (Semester - I) (New) (CBCS) Examination: Oct/Nov-2022 PHYSICS (APPLIED ELECTRONICS) **Mathematical Physics**

Day & Date: Monday, 13-02-2023 Time: 03:00 PM To 6:00 PM

Instructions: 1) Q. Nos. 1 and. 2 are compulsory.

2) Attempt any three questions from Q. No. 3 to Q. No. 7 3) Figure to right indicate full marks.

Q.1 Fill in the blanks by choosing correct alternatives given below. A)

- If A and B are orthogonal matrices, then the product AB is 1)
 - Symmetric Antisymmetric a) b)
 - Orthogonal d) Unitary C)

What is the value of a_0 in the fourier series of t^2 in the interval 2) $-\pi < t < \pi$?

a)	0	b)	$\frac{\pi^2}{2}$
c)	$\frac{\pi^2}{8}$	d)	

The solution of (y-2)p + (z-x)9 = x - y is 3)

- f(x + y + z) = xyza)
- $f(x^2 + y^2 + z^2) = xyz$ b)
- $f(x^2 + y^2 + z^2, x^2, y^2, z^2) = 0$ c)
- $f(x + y + z) = x^2 + y^2 + z^2$ d)

Laplace transform of $e^{-2t} \sin 4t$ is 4) 2 a) b) $s^2 + 4s + 20$ s-4 d) c) $s^2 + 4s + 20$

If λ is an eigen value of a non-singular matrix A then the eigen value 5) of A^{-1} is

1 a) λ b) λ d) $\frac{-1}{\lambda}$ c) $-\lambda$

For two matrices A and B, $(A + B)^{-}$ is equal to 6)

			•
a)	$A^2 + B^2 + 2AB$	b)	$A^2 + B^2 + AB$
c)	$A^2 + B^2 + AB + BA$	d)	$A^2 + B^2$

What is the value of integral $\oint f(z) dz$ around a circle of radius z with 7) its centre at the origin if $f(z) = \frac{1}{(z-1)}$

		(2 1)	
a)	Zero	b)	πί
c)	$4\pi i$	d)	2πi

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Max. Marks: 80

SLR-GQ-1

8) Find the value of $\int_{0}^{2\pi} e^{\cos\theta} \cos(2\theta - \sin\theta) d\theta$

		- 0		
a)	2π		b) d)	π
c)	π		(h	3π
0)	2		u)	
	Z			2

- 9) The eigen vectors of a Hermitian matrix are
 - Real b) Imaginary
 - c) Complex d) ± 1

10) A square matrix is said to be orthogonal if

- a) A is singular
- b) A is non-singular
- c) $A^{T}A = 1$
- d) $A = -A^T$

B) State True/False

a)

- 1) Inverse of unitary matrix is unitary matrix
- 2) Fourier transform is aa linear operator
- 3) Legendre polynomial of degree one i.e $P_1(x) = \partial$
- 4) The ODE $\frac{dy}{dx} = (x + y + 5)^2$ is separable
- 5) The order of matrix $A = \begin{bmatrix} 1 & 5 & 9 \\ 4 & 8 & 6 \end{bmatrix}$ is 2×3
- 6) The first order ODE can never be linear separable and exact at the same time

Q.2 Answer the following

- **a)** Find the eigen value of $A = \begin{pmatrix} 3 & 1 \\ 2 & 2 \end{pmatrix}$
- **b)** Find the Fourier transform of e^{-ax^2} where a > 0
- **c)** Evaluate $\oint_C \frac{1}{\sin hz} dz$, where C is the circle |z| = 4
- d) Derive an expression for 2nd order homogeneous equation with consent coefficients

Q.3 Answer the following

a) If $A = \begin{pmatrix} 1 & 2 & 2 \\ 2 & 1 & 2 \\ 2 & 2 & 1 \end{pmatrix}$ show that $A^2 - 4A - 5I = 0$ where *I*, *O* are the unit matrix

& the null matrix of order 3 respectively use this result & find A^{-1}

b) Derive a Jacobi - Bernoulli equation and solve the equation use J.B equation $y^1 + x = \frac{y}{r}$

Q.4 Answer the following

- **a)** Evaluate $\int_0^\infty \frac{\cos 3\theta}{5+4\cos \theta} d\theta$
- b) Explain the details of Parseval Theorem

Q.5 Answer the following

- a) Explain the first order linear differential education.
- **b)** In square wave expand the function

 $f(x) = 0; -\pi \le x \le 0$ $f(x) = 4; -0 \le x \le \pi$ Fourier

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Q.6 Answer the following

- a)
- Show that the eigen value of Hermitian matrix are real? Find the General solution of $x(z^2 y^2)\frac{\partial z}{\partial y} + y(x^2 z^2)\frac{\partial z}{\partial y} = z(y^2 x^2)$ b)

Q.7 Answer the following

Determine whether the following equation is exact and find its solution if it is a) exact

$$(4x^3 + 6xy + y^2)\frac{dx}{dy} = -(3x^2 + 2xy + 2)$$

Write matrix A gives below as the sum of symmetric & a skew symmetric b)

matrix
$$A = \begin{pmatrix} 1 & 2 & 4 \\ -2 & 5 & 3 \\ -1 & 6 & 3 \end{pmatrix}$$

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					SLR-G	Q-2		
Seat No.					Set	Ρ		
	M.Sc. (Semester - I) (New) (CBCS) Examination: Oct/Nov - 2022 PHYSICS (APPLIED ELECTRONICS) Solid State Physics							
		esday, 14-02-2023 To 06:00 PM			Max. Mark	ks: 80		
Instructio	2) Q.Nos.1 and 2 are compo) Attempt any three question) Figure to right indicate fu	ons f	rom Q.No.3 to Q.No.7				
Q.1 A)	Choo 1)	Dise the correct alternative Plane cut to negative x-ax a) (011) c) (110)	-			10		
	2)	Effective mass depends o a) dP/dt c) dP/dK	n b) d)					
	3)	The intrinsic concentration varies as a) T c) T ³	n of c b) d)		nductor			
	4)	Relative permittivity εr of t a) 2 c) 1	the ai b) d)	ir is 0.5 0				
	5)	The electronic polarizabilit a) $4\pi\varepsilon_0$ c) $4\pi\varepsilon_0 R^3$	ty <i>αe</i> b) d)	of a monoatomic gas is $4\pi \varepsilon_0 R$ $4\pi \varepsilon_0^2$	·			
	6)	Packing fraction of BCC is a) 74% c) 52%	s b) d)	 68% 58%				
	7)	FCC structure contains the a) Two c) Nine	e cor b) d)	ntribution of atoms. Four Six				
	8)	,	ends b) d)	on mobility. Neutron None of these				

	B)	 9) 10) Writ 1. 2. 3. 4. 5. 6. 	a) c) Nui a) c) t e Tr the Fer the Re Col	(001) (010) mber of te 2 4 ue or Fal e addition mi energy conductio Debye's te supercon ctifier rect nductance	of pentavale level in the	b) d) a simp b) d) ent imp case nateria e. resist rcond	(100) (101) ble cubio 3 8 burity cr of a p-ty als show ance. uctor be	eates a /pe se w the t	m are an n-ty micono ransitio	 /pe se ductor on fror	micondu is close	to	06
Q.2	Ans a)			ollowing	ction in deta	il							16
	a) b) c) d)	Writ Deri	e ab ve a	out dielec n express		ffectiv	e mass	of the	electro	on.			
Q.3	Ans a)			ollowing at the FC	, C is reciproca	al of B	CC.						16
	b)				rystalline, na			and a	morph	nous m	naterials		
Q.4	Ans a) b)	Give	e the		on for inter-p s effect. Deri				r pene	tratior	n depth.		16
Q.5	Ans a) b)	Clas	ssify	-	etic materials havior of ele		s in a pe	eriodic	poten	tial.			16
Q.6	Ans a) b)	Writ	e ab		and indirect colarization?		• •				nic polari	izatio	16 on.
Q.7	Ans a)			ollowing	imperfection	s in cr	wetale?	Evolai	n the	various	e defecte	e in	16
	a) b)	the o	cryst	al.	nductor? Wr		-	-					
	/												

No.	-		Set P
	N	I.Sc. (Semester - I) (New) (CBCS) Examination: Oct/Nov-2022 PHYSICS (APPLIED ELECTRONICS) Analog and Digital Electronics
			dnesday, 15-02-2023 Max. Marks: 80 To 06:00 PM
Instr	ucti	2	Question no. 1 and 2 are compulsory. Attempt any three questions from Q. No. 3 to Q. No. 7. Figure to right indicate full marks.
Q.1	A)	Mult 1)	ple choice questions. 10 A (A+B) = ? b) 1 a) AB b) 1 c) (1+AB) d) A
		2)	Master slave flip is also referred to as? a) Level triggered flip flop b) Pulse triggered flip flop c) Edge triggered flip flop d) Edge-Level triggered flip flop
		3)	Which interrupt is not level sensitive in 8085?a)RST 7.5b)RST 6.5c)RST 4.5d)RST 5.5
		4)	Which of the following flag condition is used for BCD arithmeticoperations in microprocessor?a) Sign flagb) Auxiliary carry flagc) Parity flagd) Zero flag
		5)	The AND gate output will be high if the two inputs area) 00b) 01c) 10d) 11
		6)	A one-shot is a type of multivibrator.a) Astableb) Monostablec) Timerd) b & c are correct
		7)	In 8085 microprocessor register used as a working area in CPU. a) A b) B c) H d) None of these
		8)	An Integrator has in the input terminal, for an Opamp basedcircuit.a) Resistanceb) Inductorc) Capacitord) None of these
		9)	Output impedance of IC 741 is typically Ω. a) 100 b) 1000 c) 10 d) 1
		10)	 Oscillator uses capacitive voltage divider feedback. a) Hartley b) Phase shift c) Colpit d) Wien bridge

c) Colpit d) Wien bridge SLR-GQ-3

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Set P

B) Fill in the blanks / State True or False. 06 Differential Amplifier consists of _____ transistors. 1) Data bus of 8085 microprocessor is bit. 2) SR flip flop does not accept the input entry when _____ 3) Phase shift of the Phase shift circuit at the resonance frequency is 4) 180⁰ (True/False) Switching regulator is used for high power applications. (True/False) 5) Ideal op-amp has infinite voltage gain because to obtain finite output 6) voltage. (True/False) 16 Q.2 Answer the following a) Virtual ground concept **b)** DeMorgans Theorem c) PIPO shift register **d)** Flags in 8085 Q.3 Answer the following. a) What is feedback? Explain effect of negative feedback on input resistance of 10 OpAmp. **b)** Draw and explain Integrator using 741 OpAmp. 06 Q.4 Answer the following. a) Describe 4 bit D flip-flop with timing diagram. 10 b) Draw and explain 8:1 Multiplexers. 06 Q.5 Answer the following. a) Draw and explain Phase shift Oscillator using Opamp. Obtain an expression 10 for frequency. **b)** Design a non-inverting amplifier with Av =11, Given Ib=100nA, Vi >1V. 06 Q.6 Answer the following. a) Explain inverting configuration of 3 inputs Op Amp as a summing, scaling 10 and averaging amplifier. **b)** Reduce the following logical expressions using Boolean laws: 06 $\overline{ABC} + AB\overline{C} + ABC + \overline{AB}$ Draw logic diagram of reduced expression. Q.7 Answer the following.

a) Draw and explain architecture of 8085 microprocessor.
b) Draw and explain memory write cycle of 8085 microprocessor.
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Seat No.	t			Se	t P
NO.	N	/I.Sc.	(Semester-I) (New) (CBCS) Examination: Oct/No PHYSICS (APPLIED ELECTRONICS) Classical Mechanics	ov-2022	
			ursday, 16-02-2023 1 To 06:00 PM	Max. Mar	ks: 80
Instr	uctio	2) Question no. 1 and 2 are compulsory. 2) Attempt any three questions from Q. No. 3 to Q. No. 7. 3) Figure to right indicate full marks.		
Q.1	A)	Mult 1)	iple choice questions. The Poisson bracket of $[u, p_j] = $		10
			a) $-\partial u / \partial p_j$ b) $\partial u / \partial q_j$ c) $+\partial u / \partial p_j$ d) $-\partial u / \partial q_j$		
		2)	The point transformation is the transformations ofa) Phase spaceb) configuration spacec) both a & bd) point space		
		3)	The reduced mass $\mu = $ a) $(m_1 + m_2)/m_1m_2$ b) $m_1m_2/(m_1 - m_2)$ c) $m_1m_2/(m_1+m_2)$ d) $(m_1 - m_2)/m_1m_2$		
		4)	$\begin{array}{llllllllllllllllllllllllllllllllllll$		
		5)	If eccentricity $C = 0$, then the shape of the orbit, which is forto motion under central force field will bea) Ellipseb) Circlec) Hyperbolad) Parabola	ormed due	
		6)	The Hamiltonian is defined as a) H=T-V b) H=T/V c) H=T*V d) H=T+V		
		7)	The generating function F ₂ (q, P, t) generates transitian (q, P, t) generates _	formations.	
		8)	The Phase space isdimensional space. a) 3N b) 2N c) 6N d) N		
		9)	The Poisson bracket of $[u,u] = $ a) 1 b) u^2 c) 0 d) 2u		
		10)	$ \begin{array}{ll} \text{If } m_1 \ll m_2, \text{ then the centre of mass of system coincides} \\ \text{centre of mass of } ___\ \\ \text{a) } m_1 & \text{b) } m_2 \\ \text{c) in between } m_1 \text{ and } m_2 & \text{d) } \text{ away from } m_1 \end{array} $	with the	

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SLR-GQ-4

B) Fill in the blanks or write true or false. 06 [X,Y] = [Y,X] is the property of the Poisson bracket. 1) The Hamiltonian formulation is more advantageous than the 2) Newtonian. In the Configuration space, the system is having a unique path. 3) There are three degrees of freedom for a flywheel. 4) The path of the particle is a straight line when it is moving under the 5) constant conservative force field. The Δ – variation involves time. 6) Q.2 Answer the following. 16 a) State and prove the law of conservation of linear momentum of system particles. b) Write a note on Kepler's laws of planetary motion. c) Which conditions are used to verify that the transformation is canonical? Prove any one condition. d) What is generating function? What are its different forms? Answer the following. Q.3 a) Discuss the Hamilton-Jacobi theory and derive the Hamilton-Jacobi partial 10 differential equation and its solution. b) Deduce the relation between the Hamiltonian and Lagrangian. 06 Q.4 Answer the following. Define Hamiltonian. Why Hamiltonian formulation is preferred over 10 a) Langrangian formulation. b) How the equations of motion are written in terms of Poisson brackets. 06 Q.5 Answer the following. a) What are the main features of the motion of a particle under the action of 10 central force? Show that the area swept per unit time i.e. dA/dt remains constant in such a motion. **b)** What are constraints? Explain with its example. 06 Answer the following. Q.6 a) What is Poisson Bracket? List its properties. Explain Jacobi's identity with its 10 proof. b) Distinguish between the configuration space and phase space. 06 Q.7 Answer the following. a) How a two-body problem does reduce to a single-body problem? Derive the 10 equation of motion for it. **b)** Write a note on Rutherford's scattering. 06

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M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov-2022 PHYSICS (APPLIED ELECTRONICS) Quantum Mechanics

Day & Date: Monday, 20-02-2023 Time: 11:00 AM To 02:00 PM

Instructions: 1) Q. Nos. 1 and. 2 are compulsory.

- 2) Attempt any three questions from Q. No. 3 to Q. No. 7
- 3) Figure to right indicate full marks.

Q.1 A) Choose correct alternative. (MCQ)

- 1) Which of the following is the velocity at which a given crest moves?
 - a) The phase velocity ω b) Group velocity
 - c) Particle velocity d) Sound velocity

2) In which of the following effect, the electrons are emitted from a metal surface illuminated by the ultraviolet radiation.

- a) Photoelectric effect b) Diffraction
- c) Compton scattering d) Interference
- 3) The relationship between velocity v, momentum p and wavelength λ is given by

a)
$$p = hv$$

b) $p = \frac{h}{\lambda}$
c) $p = \frac{mv}{c}$
d) $p = \frac{\lambda}{h}$

- 4) The Schrodinger's wave equation for a particle moving in one dimension is given by
 - a) $\frac{d^2\psi}{dx^2} + \frac{8\pi^2m}{h^2}(E V)\psi = 0$

b)
$$\frac{d^2\psi}{dx^2} - \frac{8\pi^2 m}{h^2} (E - V)\psi = 0$$

c)
$$\frac{d^2\psi}{dx^2} + \frac{8\pi^2 m}{h^2} (E+V)\psi = 0$$

d) $\frac{d^2\psi}{dx^2} - \frac{8\pi^2 m}{h^2} (E+V)\psi = 0$

- 5) The Born interpretation of ψ is that
 - a) $|\psi * \psi|$ dr is proportional to the probability of finding the electrons in an infinitesimal region between r and r + dr
 - b) $|\psi * \psi| dr$ is inversely proportional to the probability of finding the electrons in an infinitesimal region between r and r + dr
 - c) $|\psi * \psi| dr$ is proportional to the negative probability of finding the electrons in an infinitesimal region between r and r + dr
 - d) $|\psi * \psi| dr$ is not related with the probability of finding the electrons in an infinitesimal region between r and r + dr
- 6) Acceptable / well behaved wave functions are those which satisfy the
 - a) Ψ must be single valued
 - b) Ψ and its first derivative with respect to its variables are continuous
 - c) For bound states, Ψ must vanish at infinity
 - d) All of the above

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Max. Marks: 80

SLR-GQ-6

7) The zero-point energy of an electron in a one dimensional box is given by

a)

$$E_{zero \ point} = \frac{h^2}{4m_e a^2}$$
b)

$$E_{zero \ point} = \frac{h^2}{8m_e a^2}$$
c)

$$E_{zero \ point} = -\frac{h^2}{8a^2}$$
d)

$$E_{zero \ point} = \frac{h^2}{8m_e}$$

8) The potential energy of particle in harmonic oscillator is given by a) $V = kx^2$ b) 1

c)
$$V = \frac{1}{4}kx^2$$

 $V = \frac{1}{4}kx^2$
 $V = \frac{1}{8}kx^2$

9) The first theory of chemical bonding is given by_____

- a) G. N. Lewis in 1916 b) G. N. Mendis in 1916
- c) G. N. Lewis in 1961 d) G. N. Mendis in 1906
- 10) The Laplacian operator in quantum mechanics is defined

a)

$$\nabla^{2} = \frac{\partial^{2}}{\partial x^{2}} - \frac{\partial^{2}}{\partial y^{2}} + \frac{\partial^{2}}{\partial z^{2}}$$
b)

$$\nabla^{2} = \frac{\partial^{2}}{\partial x^{2}} + \frac{\partial^{2}}{\partial y^{2}} + \frac{\partial^{2}}{\partial z^{2}}$$
c)

$$\nabla^{2} = \frac{\partial^{2}}{\partial x^{2}} + \frac{\partial^{2}}{\partial y^{2}} - \frac{\partial^{2}}{\partial z^{2}}$$
d)

$$\nabla^{2} = \frac{\partial^{2}}{\partial x^{2}} - \frac{\partial^{2}}{\partial y^{2}} - \frac{\partial^{2}}{\partial z^{2}}$$

B) Fill in the blanks or Write true /false

- 1) The condition for an operator \hat{A} to be hermitian is given by _____
- 2) The minimum energy required to remove an electron from the hydrogen atom in its ground state is the _____.
- The atomic unit of magnetic moment is known as _____
- 4) Write whether following statement is true or false. The electron inside the box is not at rest even at 0 K
- Write whether following statement is true or false.
 It is assumed that electrons in molecules occupy certain orbitals, which extend over all the nuclei in a molecule.
- 6) Write whether following statement is true or false. The general concept of molecular orbitals and of the building up principle using molecular orbitals was developed in 1927 by Hund and Mulliken and in 1929 by Lennard Jones.

Q.2 Answer the following questions.

- a) Discuss the wave and particle nature of radiation
- **b)** Write a note on break down of Born-Oppenheimer approximation.
- c) State the postulates of quantum mechanics
- d) Write a note on Normalization and Characteristics of Eigen functions of harmonic oscillator

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Q.3	Ans a) b)	wer the following Obtain the Schrodinger's wave equation in three dimensions. Explain the Eigen functions of the position operator and Dirac delta function.	10 06
Q.4	Ans a) b)	wer the following Obtain the expression for energy of particle in harmonic oscillator. With neat diagram explain the shape of atomic orbital.	10 06
Q.5	Ans a) b)	wer the following. Obtain the expression for ground state energy of hydrogen atom. Explain the self-consistent field method in calculation of the ground state energy and wave functions of many electron atoms.	10 06
Q.6	Ans a) b)	wer the following. Describe the molecular orbital treatment of hydrogen molecule. Apply the Born-Oppenheimer approximation and LCAO molecular orbital theory to Hydrogen molecule ion.	10 06
Q.7	Ans a)	wer the following. With a diagram of P, Q, R Branches, explain the Vibration and vibrational	10
	b)	spectra of diatomic molecules. Write a note on Eigen functions of position operator.	06

	11.3	ι. (3	PHYSICS (APPI	_IED	ELECTRONICS)
			uesday, 21-02-2023 // To 02:00 PM		Max. Marks:
Instr	uctio		 Q. No 1 and 2 are comp Attempt any three quest Figures to the right indic 	tions f	rom Q. No. 3 to 7
Q.1	A)	Cho 1)	The scalar potential for c a) $V \propto \frac{1}{r^2}$ c) $V \propto \frac{1}{r^4}$	uadru b)	-
		2)	1		ic field over a surface is
		3)	A wire wound in the form than when it is unwound a) Smaller c) Nearly equal	b)	solenoid has self-inductance Equal Larger
		4)	The scalar potential is du a) Charge density c) Surface current		
		5)		of mag	gnetic field, above and below the continuous
		6)	The electric field inside a a) Greater than zero c) Zero	b) d)	luctor is Less than zero none of these
		7)	Angular distribution of en low velocity is proportion a) $Sin^2\theta$ c) $\frac{1}{Sin^3}$	•••	due to accelerated charged particle at $\frac{1}{\sin^2 \theta}$

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M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov - 2022

SLR-GQ-7

80

10

a)	Sin ² 0	b)	Sin ³ 0
c)	1	d)	1
	Sin_{θ}^{3}		Sin_{θ}^2

- The radiation from an oscillating electric dipole is generally _____. 8)
 - a) Transverse electric Zero b)
 - c) Positive d) Transverse magnetic

Set Ρ 9) Unit of Poynting vector is _____.

a)	W/m	b)	W.m
c)	W/m²	d)	m/W

		 10) For radiation fields the ratio E/B is always equal to a) One b) 1/velocity of light c) velocity of light d) less than velocity of light 			
Q.1	B)	 Fill in the blanks. 1) When a high-speed electron hits a metal target, it rapidly decelerates, giving off what is called 2) A charge Q is uniformly distributed on the surface of a cube and there i no other charge in consideration. Divergence of electric field is 3) Amount of electrostatic energy stored in unit volume of electric field is 4) Magnetic field does work 5) Two particles with identical charges and mass collide, there is 6) The Lorentz gauge condition is 	06 s		
Q.2	Ans a) b) c) d)	wer the following. What are boundary conditions? State the Coulomb and Lorentz gauge conditions. What are scalar and vector potentials? Write the Maxwell's equations in differential form.	16		
Q.3	Ans a) b)	4π r ²			
Q.4	Ans a) b)	wer the following. Derive an expression for the electric potential at a distance 'r' due to a point charge. Explain the concept of Maxwell's displacement current.	16		
Q.5	Ans a) b)	Swer the following. State and prove Poyntings theorem and explain the significance of Poyntings vector. Obtain electromagnetic wave equations in conducting medium.	16		
Q.6	Ans a) b)	wer the following. Obtain the Fresnel's relation for the polarization parallel to the plane of incidence. What is Hertz potential and explain its importance?	16		
Q.7	Ans a) b)	wer the following. Derive the relation for total power radiated by electric dipole. Explain radiation from half wave antenna.	16		

Max. Marks: 80

M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov - 2022 PHYSICS (APPLIED ELECTRONICS) Statistical Physics

Day & Date: Wednesday, 22-02-2023 Time: 11:00 AM To 02:00 PM

Instructions: 1) Q. Nos. 1 and 2 are compulsory.

- 2) Attempt any three questions from Q. No.3 to Q. No.7.
- 3) Figure to the right indicates full marks.

Q.1 A) Choose Correct Alternative:

- 1) Which one of the following definitions best describes the concept of work?
 - a) The flow of energy from one object or substance to another due to a difference in temperature
 - b) The flow of energy from one body to another through uniform molecular motion
 - c) The force associated with molecular motion
 - d) The random motion of molecules in a gas at low pressure
- 2) An isolated system is best described by which one of the following statements.
 - a) Neither matter nor heat can pass into or out of the system
 - b) The system has a boundary which allows heat to be transferred but does not allow material to pass into or out of the system
 - c) The system has a diathermic boundary
 - d) A system which has reached thermal equilibrium with its surroundings
- 3) Which one of the following statements describes a path function?
 - a) A property of a system that depends only on the current state of the system, not on the path the system took to reach that state
 - b) A property of a system that depends on the path taken between the initial and final states.
 - c) The sum of kinetic and potential energy contained in a substance
 - d) The heat energy absorbed by a system at constant pressure
- 4) Which one of the following equations defines the enthalpy of reaction, ΔH , for a reaction occurring at constant pressure that does expansion work? All terms have their usual meanings.
 - a) ΔH = ΔU
- b) $\Delta H = \Delta U + p \Delta V$
- c) $\Delta H = \Delta G T\Delta S$ d) $\Delta H = q + w$

- 5) Gibbs paradox in statistical mechanics is related to.
 - a) Additive property of the energy
 - b) Additive property of the momentum
 - c) Additive property of the entropy
 - d) Additive property of the temperature
- 6) What is a process during which the pressure remains constant?
 - a) Isometric process b) Isobaric process
 - c) Isochoric process d) Isothermal process
- 7) What type of system energy is related to the molecular structure of a system?
 - a) Macroscopic form of energy
 - b) Microscopic form of energy
 - c) Internal energy
 - d) External energy
- 8) Consider the three collections of particles (ensembles) named micro canonical, canonical and grand canonical. Which one physical property is constant in all three ensembles? Total number of particles N incorrect
 - a) Pressure, p
 - b) Temperature, T
 - c) Volume, V
 - d) Total number of particles N
- 9) Consider the general labelling of systems as open, closed, or isolated. The first allows the exchange of matter and energy with its surroundings; the second allows only the exchange of energy, whereas the third allows no exchange at all. Which one of the following statements is correct?
 - a) An isolated system obeys the rules of the canonical ensemble.
 - b) An open system obeys the rules of the canonical ensemble.
 - c) An open system obeys the rules of the microcanonical ensemble.
 - d) A closed system obeys the rules of the microcanonical ensemble.
- 10) The ensemble which allows the subsystem to allow exchange of energy as well as
 - a) Canonical ensembles
 - b) Micro canonical ensembles
 - c) Grand canonical ensembles
 - d) Both a and c

B) State True or False:

- 06
- 1) The Kinetic Energy of the particle is dependent on Temperature only. (True/False)
- 2) If a liquid crystallises in to a solid, entropy will be decrease. (True/False)
- 3) Gibbs paradox in statistical mechanics is related to additive properties of entropy. (True/False)

		4) 5) 6)	The Fermi energy (Ef) of the white dwarfs is 10 MeV. (True/False) A system can exist in a state of negative temperature because the total energy E has an upper bound. (True/False) If the system is known to be in a state of equilibrium, the corresponding ensembles must be Hamiltonian. (True/False)	
Q.2	Ans a) b) c) d)	State Expl Expl State	the following. e and explain the Bose-Einstein condensation. ain the Pauli Paramagnetism. ain the concept of canonical, and microcanonical ensemble. e the Density of state in phase space based on classical and ntum physics.	16
Q.3	a)	Deriv ense	he following. ve an expression for partition function of ideal gas in grand canonical emble.	16
	b)		e and explain the planks distribution law and derive the necessary ession for it.	
Q.4	Ans a) b)	State What conc	the following. e and derive the equipartition theorem at is Ensemble? What are different type of ensemble? Explain the cept of ensemble average and discuss the concept at stationary emble.	16
Q.5	Ans a) b)	State Show	he following. e and explain nature of particle in Boson- Einstein statistics. w that the change in the entropy due to mixing of two ideal gases Its in to the Gibb's paradox.	16
Q.6	Ans a) b)	Deso Deriv	he following. cribe in detail the concept of Density Distribution in phase space. ve an expression for Entropy, Gibb's Free energy for canonical emble.	16
Q.7	Ans a) b)	State Shov	he following. e and describe the Liouville's equation. w that the change in the entropy due to mixing of two ideal gases Its in to the Gibb's paradox	16

	M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov-2022 PHYSICS (APPLIED ELECTRONICS) Semiconductor Physics					
Time	Day & Date: Monday, 13-02-2023 Time: 11:00 AM To 02:00 PM Instructions: 1) Q. No. 1 & 2 are compulsory. 2) Attempt any three questions from Q. 3 to 7. 3) Figures to the right indicate full marks.					
Q.1	A)	Cho 1)	Dose correct alternative1Epitaxial techniques have been used for the growth of epilayers ofIII -V and, II -VI compound and other materials.a) metalsb) insulatorsc) semiconductorsd) conductors	0		
		2)	The maximum packing factor for a SC lattice of identical atoms with a lattice constant of 20 A ⁰ will bea) 0.52b) 0.68c) 0.34d) 0.74			
		3)	The initial process that occur in the formation of a crystal is a) growth b) nucleation c) atomic bonding d) clusters			
		4)	Czochralski method is crystal growth from a) melt b) vapour c) solution d) solid			
		5)	 A semiconductor absorbs photons with energies a) smaller than band gap energy only b) equal to the band gap energy only c) equal to the band gap or larger d) equal to the band gap or smaller 			
		6)	The driving force needed for the nucleation and growth of crystal isreferred asa) molecular forceb) super saturationc) growth forced) atomic force			
		7)	In indirect recombination the electron and hole pairs recombine at recombination level; <i>Er</i> in steps. a) 2 b) 3 c) 4 d) 5			
		8)	 The relation between frequency and wavelength is known as a) the dispersion relationship b) de Broglie relation c) Cauchy's relation 			

- c) Cauchy's relationd) Planck relation

Set P

Seat No.

- 9) Which of the three semiconductors, Ge, Si and GaAs has a direct bandgap?
 - a) Ge and GaAs
- Si and GaAs b)
- c) GaAs Ge and Si d)
- 10) Which of the following semiconductor has indirect band gap?
 - a) Ge and GaAs c) GaAs
- Si and GaAs b) d) Ge and Si
- Q.1 B) Fill in the blanks OR write True /False
 - For lightly doped junction's electron tunneling is dominant 1) phenomenon. (True/False)
 - 2) In a semiconductor, the electrons occupy states near the top of the conduction band. (True/False)
 - A semiconductor with band gap of about 2 eV wide, allows only long 3) wavelengths and the red part of the visible spectrum to transmit through it. (True/False)
 - 4) First step in crystal growth is the transport of atoms through solution. (True/False)
 - 5) Epitaxy means growth of many crystal films on top of a crystalline substrate. (True/False)
 - epitaxy is a process of depositing epitaxial thin films from molecule 6) of atomic beams on a heated substrate under UHV conditions.

Q.2 Answer the following.

- Write a note on direct recombination of electrons and holes. a)
- Discuss bonding forces in semiconductors. b)
- What are the advantages of Epitaxial technology? c)
- Explain the term nucleation rate and induction time. d)

Q.3	Ans a) b)	swer the following. Describe steady state carrier injection in case of semiconductor. Explain with neat diagram Czocharalski method of crystal growth.	16
Q.4	Ans a) b)	swer the following. Discuss in detail "Effective mass" of an electron in a band. Explain with neat diagram Liquid Phase Epitaxy.	10 06
Q.5	Ans a) b)	Swer the following. Obtain an expression for electrical conductivity (σ) and mobility (μ) in case of semiconductors. Explain with neat diagram Molecular Beam Epitaxy.	16
Q.6	Ans a)	swer the following. Explain Zone melting method of crystal growth.	16

- Write a note on high field effects in semiconductors. b) Q.7 Answer the followings. 16 Explain indirect recombination and trapping of charge carriers of a) semiconductors.
 - Explain theory of nucleation and growth. b)

06

	Day & Date: Tuesday, 14-02-2023 Max. Marks: 8 Time: 11:00 AM To 02:00 PM				
Instructio		 Q. Nos. 1 and 2 are compulso Attempt any three questions from 3) Figure to right indicate full mark 	om Q. N	lo. 3 to Q. No. 7	
Q.1 A)	Chc 1)	hose correct alternative. (MCQ) In the case of 1 st order, Stark ef the ground state splits into a) 2 levels		1 the hydrogen atom (Z =1) 3 levels	
		c) 4 levels	d)	does not split	
	2)	The rotational constant for H ³⁵ C What is the value of B for ² D ³⁵ C (Given: atomic masses (in kg): ¹ 35 Cl = 1.673 x 10 ⁻²⁷ , ³⁷ H = 61.38 a) 5.44 cm ⁻¹ c) 6.44 cm ⁻¹	l? ^I H = 1.6	673 x 10 ⁻²⁷ , ² D = 58.06 x 10 ⁻²⁷ ,	
	3)	The equilibrium vibration freque 2990 cm ⁻¹ . The ratio of the freque overtone band and the fundame the oscillator to be anharmonic, a) 0.005 c) 0.05	uencies ental sp	corresponding to the first ectral lines is 1.96. Considering	
	4)	What is the moment of inertia I_B 143 pm? Atomic masses are: ¹ H a) 3.33 x 10 ⁻⁴⁷ kg.m ² c) 2.34 x 10 ⁻³⁷ kg.m ²	H=1.008	3 amu, ⁷⁹ Br = 78.92 amu 3.00 x 10 ⁴⁶ kg.m ²	
	5)	Put the energies of the $K\alpha, K\beta$, order of increasing energy (from a) $L\alpha, K\alpha, K\beta$ c) $K\alpha, L\alpha, K\beta$	n smalle b)	•	
	6)	The bond order for the O ₂ molec a) 1 c) 2.5	cule is _ b) d)	2 0	
	7.	,	,	served in the case of Orthoheliun $2^{3}P_{1} \longrightarrow 2^{1}S_{0}$	

Q.1

- m
 - b) $2^{\circ}P_{1}$
 - a) $2^{3}P_{0,1,2} \longrightarrow 2^{3}S_{1}$ c) $2^{3}P_{0,1,2} \longrightarrow 2^{3}S_{1}$ → 1¹S₀ 3^1P_1 d)

Seat No.

M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov - 2022 PHYSICS (APPLIED ELECTRONICS) **Automatic, Molecular Physics**

80

SLR-GQ-11 Set Ρ

- 8) The total number of emission lines observed during the transition of electrons from $3^2P_{3/2}$ to $3^2S_{3/2}$ are ____.
 - a) 2 b) 4
 - c) 6 d) 8
- 9) The spectroscopic symbol for the ground state of AI (Z = 13) is 2P_{1/2}. Under the action of a strong magnetic field (when L-S coupling can be neglected) the ground state energy level will split into _____
 - a) 3 levels b) 4 levels
 - c) 5 levels d) 6 levels

10) The fine structure of atomic spectral lines arises from

- a) Electron spin-orbit coupling
- b) Interaction between electron and nucleus
- c) Nuclear spin
- d) Stark effect

B) Fill in the blanks OR Write true /false

- 1. According to Moseley's law, the frequency of a spectral line in an X-ray spectrum varies as a square of the atomic number of the element. (True/False)
- 2. The shortest wavelength observed in the Paschen series of hydrogen spectra is _____.
- The spectral term separation ΔT is expressed in terms of cm⁻¹ which is caused due to spin-orbit interaction and is related to the atomic number Z by Z⁻⁴. (True/False)
- 4. The energy of the K α X-ray of sodium (Z = 11) is 1.02 keV.
- 5. The Lande's g-factor for $8G_{1/2}$ is 4/3
- 6. Oxygen has the electronic configuration 1s22s22p4. In the ground state, the total ms of all 8 of the electrons has the largest possible value consistent with the Pauli principle is 1.

Q.2 Answer the following questions.

- A) Write an electronic configuration of Na₂ (Na, Z = 11) and S₂ (S, Z = 16) diatomic molecules in accordance with molecular orbital approach and state the bond order in each case.
- B) Find the possible multiplicities x of the terms of the types (a) xD_2 ; (b) $xP_{3/2}$
- C) What is Stark effect? discuss the weak-field Stark effect in hydrogen for $H\alpha$ line.
- D) From the following data, find the energy required to dissociate a KCI molecule into a K atom and a CI atom. The first ionization potential of K is 4.34 eV; the electron affinity of CI is 3.82 eV; the equilibrium separation of KCI is 2.79 Å. (Hint: Show that the mutual potential energy of K⁺ and CI⁻ is (14.40/R) eV if R is given in Angstroms).

$$(\frac{e^2}{4\pi\varepsilon_0} = 1.44 \times 10^{-9} \, eV.m)$$

06

16

Q.3 Answer the following questions.

- A) i) Discuss the rotational spectrum of a diatomic molecule treated as a non-rigid rotator.
 - ii) The rotational spectrum of ⁷⁹Br¹⁹F shows a series of equidistance lines 0.71433 cm⁻¹ apart. Calculate the rotational constant, B, and hence the moment of inertia and bond length of the molecule. Determine the wave number of the J = 9 to J = 10 transition, and find which transition gives rise to the most intense spectral line at room temperature, (say 300 K). Calculate the number of revolutions per second which the BrF molecule undergoes when (a) the J = 0 state (b) J = 1 state, and (c) the J = 10 state. (Atomic masses in kg: ⁷⁹Br = 131.03 x 10⁻²⁷, ¹⁹F = 31.55 x 10⁻²⁷; h = 6.626 x10⁻³⁴ Js, c = 2.998 x 10⁸ m/s, k = 1.381 x 10⁻²³ J/K) Hint: Use E= ½ I ω^2
- B) i) Discuss the basic foundation behind the magnetic spin resonance spectroscopy techniques?
 - ii) Differentiate between nuclear magnetic resonance and electron paramagnetic resonance spectroscopic techniques,
 - iii) Show how many signals you will see in the electron spin resonance spectrum of H-atom considering nuclear hyperfine interaction. Sketch the predicted spectrum in first derivative form and label it properly.
 - iv) If the observed chemical shift of a proton is 200 Hz from tetramethylsilane (CH₃)₄Si and instrument frequency is 60 MHz, what is the chemical shift in terms of δ ? Express it in τ value.

Q.4 Answer the following questions.

- A) i) Draw a neat labelled schematic diagram showing electronic, vibrational and rotational energy levels of a molecule and comment on their individual separations with typical energy/wavenumber values.
 - ii) Give a brief account of Franck-Condon principle and discuss how it is useful in explaining the intensity distribution in absorption bands of molecules based on internuclear separations of upper and lower electronic states.
 - iii) Obtain the number of vibrational modes for the following molecules and sketch them
 - a) H_2O b) CO_2
- B) i) In a multielectron atom, consider two identical particles (electrons, noninteracting). Let ψ_{α} and ψ_{β} be the eigenfunctions corresponding to the states α and β , in which the two particles can be found. Considering total eigenfunctions, show that the two particles can not be in a state with the same set of quantum numbers.
 - ii) Evaluate the Lange' g factor for the ${}^{3}P_{1}$ state in 2p3s configuration of ${}^{6}C$. On the application of a magnetic field B = 0.1 tesla, calculate the Zeeman splitting of the state ΔE in joules. ($\mu_{b} = 9.2740 \times 10^{-24} \text{ J/T}$)

iii) Nitrogen (Z = 7) has three electrons in the 2p level (in addition to two electrons each in the 1s and 2s levels), (a) Consistent with the Pauli principle, what is the maximum possible value of the total M_s of all seven electrons? (b) List the quantum numbers of the three 2p electrons that result in the largest total M_s . (c) If the electrons in the 2p level occupy states that maximize M_s , what would be the maximum possible value for the total M_L ? (d) What would be the maximum possible total M_L if the three 2p electrons were in states that did not maximize M_s ?

Q.5 Answer the following questions.

A) What do you mean by spin-orbit interaction? Calculate the change in total energy of the atom due to spin-orbit coupling. Find the magnitude of spin-orbit energy for $2_{P_{\frac{3}{2}}}$ state of the hydrogen (Z=1) atom. The radius of the

orbit is $3a_0 = 1.5$ Å

е

$$= 1.6 \times 10^{-19}$$
C, $\hbar = 6.58 \times 10^{-16}$ eV.s, $m = 9.1 \times 10^{-31}$ kg

$$c = 3 \times 10^8 m s^{-1}$$
; $\varepsilon_0 = 8.8542 \times 10^{-12} F. m^{-1}$ spin g -factor $g_s = 2$

(Bohr radius $a_0 = 0.529$ Å, \vec{S} . $\vec{L} = \frac{\{j(j+1) - l(l+1) - s(s+1)\hbar^2\}}{2}$; $\langle \frac{1}{r^3} \rangle = \frac{z^3}{a_0^3 n^3 l(l+\frac{1}{2})(l+1)}$

- B) i) Discuss the vibrational-rotational spectra of a diatomic molecule by showing P, Q and R branches with proper selection rules,
 - ii) Designate proper branches (P, Q and R) for the following type of vibrations of a heteronuclear diatomic molecule
 - a) Symmetric stretching mode in which dipole vibrate parallelly along the bond length.
 - b) Bending mode in which dipole vibrate perpendicularly along the bond length,
 - iii) Explain why vibrational-rotational spectra cannot be obtained for homonuclear diatomic molecules having identical nuclei?

Q.6 Answer the following questions.

- A) Discuss the Paschen Back effect for one vale nce electron system by considering the principal doublet (i.e. D1 and D2 lines) ²S_{1/2} ← ²P_{1/2,3/2} transitions of sodium. Justify the phenomenon of Paschen Back effect by considering magnetic interaction energy i. e. ΔE
- B) Find the most probable radius for the electron of a hydrogen (Z =1) atom in the 1s states. Given, $P_{1,0}(r) = \frac{4r^2}{a_0^3}e^{\frac{-2r}{a_0}}$. Calculate the average orbital radius of a 1s electron in the hydrogen atom. What is the probability of the electron in the 1s state of the hydrogen atom being at a radius greater than the Bohr radius a_0 ? (Given, e = 2.71818) Given: $\int_0^\infty x^m \cdot e^{-ax^n} dx = \frac{1}{n} \frac{\Gamma(\frac{m+1}{n})}{a^{(m+1)/n}}$; $\Gamma(n) = (n-1)!$

16

16

Q.7 Answer the following questions.

- A) Explain the valence band theory of Heitler- London i.e. Quantum mechanical treatment of Hydrogen (H₂) Molecule.
- B) i) What are non-equivalent and equivalent electrons? Is it possible to have two equivalent electrons in the same atom? Calculate the spectral terms for non-equivalent (s,s) (s,p) and (p,p) electrons and for two equivalent (s²) and (p²) electrons.
 - ii) What do you mean fine structure? With neat labelled diagram discuss the fine structure of doublets for a) ${}^{2}P_{1/2}$ and ${}^{2}P_{3/2}$ and b) ${}^{2}D_{3/2}$ and ${}^{2}D_{5/2}$ states with justification based on magnitude of ΔT_{ls}
 - iii) Calculate the ESR frequency of an unpaired electron in a magnetic field of 3000 G

(0.30 T). (g = 2.00, μ_B = 9.273 x 10⁻²⁴ J/T, h = 6.626 x 10⁻³⁴ Js)

Set

M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov-2022 PHYSICS (APPLIED ELECTRONICS) **Communication System**

Day & Date: Wednesday, 15-02-2023 Time: 11:00 AM To 02:00 PM

Instructions: 1) Question no. 1 and 2 are compulsory.

- 2) Attempt any three questions from Q. No. 3 to Q. No. 7.
- 3) Figure to right indicate full marks.

Q.1 A) Multiple choice questions.

- Name the process of recovering the original information signal from 1) the modulated wave at the receiver end ____
 - a) Attenuation Demodulation b)
 - c) Modulation d) **Bandwidth**
- In Low level Amplitude Modulation ____ 2)
 - a) Modulation is done at lower power of carrier and modulating signal
 - b) Output power is low
 - c) Power amplifiers are required to boost the signal
 - d) All of the above

3) In an SSB transmitter, one is most likely to find a _____.

- a) class C audio amplifier
- b) tuned modulator
- c) class B RF amplifier
- d) class A RF output amplifier

4) The output of a PLL frequency demodulator is taken from the _____. VCO b)

- a) low-pass filter
- c) phase detector d) None of these
- 5) The ratio between the modulating signal voltage and the carrier voltage is called?
 - a) Amplitude modulation b) Modulation frequency
 - c) Modulation index Ratio of modulation d)
- The pulse position modulation is a type of _____ modulation. 6)
 - a) Analog b) Angle c) Digital
 - d) None of the above
- 7) In a delta modulation system, granular noise occurs when the _____.
 - a) Modulating signal increases rapidly
 - b) Pulse rate decreases
 - c) Pulse amplitude decreases
 - d) Modulating signal remains constant
- _____ transmission, the channel capacity is shared by both 8) In communicating devices at all times.
 - .simplex a) b) .half-duplex
 - c) .full-duplex .half-simplex d)

Max. Marks: 80

SLR-GQ-12

10

Ρ

		9)	Unipolar, bipolar, and pol a) line c) NRZ	lar encodin b) d)	g are types of block Manchester	encoding.	
		10)	In transmission, or more stop bits (1s) at t a) synchronous c) isochronous	we send 1	()		
	B)	Write 1) 2) 3) 4) 5) 6)	e true or false. In High level Amplitude M of carrier and modulating TDMA allocates a single TDM is less immune to c In ASK, the amplitude of elements. Both frequency The area covered by CDI Step size is effectively mage	i signal. time per fra ross-talk in the carrier y and phase MA is large	ame to different u channel than FI signal is varied t e remain constar compared to TI	users. DM. o create signal nt. DMA.	06
Q.2	a) b) c)	Explai What What	ne following in TDMA. is PSK? is delta modulation? in quantization of signal.				16
Q.3		With a	ne following. a neat block diagram, expla in block diagram of VCO.	ain low leve	el modulated AM	transmitter.	10 06
Q.4		What	ne following. is FM? Explain in detail du ss sampling theorem with	-			10 06
Q.5	An: a) b)	Discus 1) 2) I	ne following. ss briefly: TDM FDM ⁄ describe generation of P ⁻	TM.			10 06
Q.6	An: a) b)	Explai	ne following. in in detail ASK with its mo in PLL as FM detector.	odulator and	d demodulator.		10 06
Q.7	An: a)	Explai 1) 3 2) 3	ne following. in the following modes of t Simplex Half duplex Full duplex Asynchronous	ransmissio	n.		10
	b)	1)	in the following: Unipolar Bipolar				06

2) 3) ырс RZ

Seat		
No.		Set P
M.So	c. (Se	emester - IV) (New) (CBCS) Examination: Oct/Nov-2022 PHYSICS (APPLIED ELECTRONICS) Semiconductor Devices
Time: 03:0	0 PM ns: 1) 2)	nday, 20-02-2023 To 06:00 PM Q. Nos.1 and 2 are compulsory. Attempt any three questions from Q. No. 3 to Q. No. 7 Figure to right indicate full marks.
Q.1 A)	Cho 1)	ose correct alternatives.10Ideally solar cells havingseries resistance andshuntseries resistance andshunta) Infinite, Zerob) Low, Highc) Zero, infinited) Not possible to measure
	2)	CMOS is popular due to a) Low noise immunity b) High power consumption c) Low power consumption d) High power dissipation
	3)	The intercept ofvariation corresponds to the built-in potential, V _{bi} , of Schottky device. a) $1/C^2$ Vs V b) C^2 Vs1/V c) C^2 VsV d) $1/C^2$ VsV ²
	4)	GaAs is better for MESFET than silicon due to a) Low mobility b) Temperature stability c) Low power levels d) High capacitance
	5)	The lasing threshold current density for junction LASER is lowest. a) homo b) graded c) hetero d) double hetero
	6)	The switching ON behavior of SCR is based on a) regenerative b) Blocking c) breakdown d) Etching
	7)	 A CCD involvesactions. a) charge storage and transfer b) only storage c) only charge transfer d) charge storage and loss
	8)	Two valley model of TEDs based on GaAs is proposed by a) BCS b) BBS c) RWH d) NWH

		 9) The condition hv < Eg causes of light in semiconductor. a) absorption b) transmission c) reflection d) modulation 10) Thicker oxide layer of MOSFET reduces its a) bias b) field strength c) work function d) fermi energy 	
	b)	State True or False/Fill in gaps.01)The potential well is created by applying positive voltage to p -	6
		substrate.	
		 LASERS convert electrical energy to optical energy. Sum of α 1 and α 2 must be Zero for SCR to become ON. The drift of stable domains in TEDs is attainable in loaded circuits. 	
		 5) HFD collapses when the field outside drops belowfield. 6) The life time of charge carriers to emit fluorescence isseconds. 	
Q.2			6
	a) b) c) d)	LASCR Heterostructures Laser. Operating modes of GaAs Gun Oscillator. GTOs	
Q.3	a)	5 1	0
	b)	mechanism in MS junction. Charge trapping in MOSFET. 0	6
Q.4	a) b)	Discuss in brief various methods of triggering pnpn device.1Reverse conducting thyristor0	0 6
Q.5	a)	5 1 5	0
	b)	effect. How performance of CCD is improved. Obtain an expression of drain current in MOSFET. 0	6
Q.6	a)	Explain IR and Visible LED. Discuss in detail the operating principle of 1 LED.	0
	b)		6
Q.7	a)	51 5 51	0
	b)	some common semiconductors relative to the optical spectrum. Explain the conditions of absorption of light by semiconductor.	6

Set **PHYSICS (APPLIED ELECTRONICS)** Nuclear and Particle Physics Max. Marks: 80 2) Attempt any three questions from Q. No. 3 to Q. No. 7. 3) Figure to right indicate full marks. The ratio will be _____. Where, R is the mean nuclear radius.0.5 1) a) 0.5 b) 2 c) 0.2 d) 4 2) Simplest two nucleon system exists in nature is of _____ a) p-p b) n-n d) c) n-p Does not exist What is the correct sequence of shell closure according to extreme 3) single particle shell model? a) 2, 6, 10, 14, 18, 32 b) 2, 8, 18, 32, 50, 86 c) 2, 8, 20, 50, 82, 126

d) 2, 8, 20, 40, 82, 126

In a typical nomenclature of nuclear reaction _ 4)

- a) is incident photon and n being outgoing particle
- b) n is incident particle and photon is out-going
- c) Both n and are incident particles
- d) Both n and are out-going particles
- 5) Nucleons in the nucleus of an atom are _____.
 - a) Uniformly distributed up to a certain distance and then falls off sharply at the boundary
 - b) They are dense at the center and then distribution falls sharply at the boundary
 - c) Distribution is even and uniform at the centre as well as at the boundary.
 - d) Distribution is uneven everywhere.
- Nuclear forces between the nucleons are ____ 6)
 - a) Central force b) Non-central forces
 - c) Purely Coulombic forces d) Cohesive forces

Ρ

M.Sc. (Semester - IV) (New) (CBCS) Examination: Oct/Nov-2022

Day & Date: Tuesday, 21-02-2023

Time: 03:00 PM To 06:00 PM

Seat

No.

Instructions: 1) Question Nos.1 and 2 are compulsory.

Q.1 A) Choose the correct alternatives from the options.

SLR-GQ-15

- 7) The height of potential barrier faced by an alpha-particle inside the nucleus is _____.
 - a) 31.2 MeV b) 31.2 KeV
 - c) 31.2 GeV d) 31.2 eV
- 8) In a typical nomenclature of nuclear reaction, _____
 - a) is parent, is incident photon, is daughter and n being outgoing particle
 - b) is parent, n is incident particle, is daughter and photon is outgoing
 - c) is daughter, n is incident particle, is parent and photon is outgoing
 - d) is parent, is daughter, n and both are out-going particles
- 9) A proton is stopped in an ionization chamber producing ion pairs. Average energy required to produce an ion pair is 35 eV. What is the kinetic energy of proton entering the ionisation chamber?
 - a) 3.5 MeV b) 35 MeV
 - c) 3.5 GeV d) 35 GeV
- 10) The average binding energy per nucleon of nucleus is _____. [Given: neutron mass m_n = 1.008665 u, proton mass m_p =1.007825 u, where 1 u = 931.5 MeV/c²]
 - a) 7.07MeV b) 28.3 MeV
 - c) 8.5 MeV d) 36 MeV

B) Fill in the blanks OR Write True/False.

- 1) Nuclear forces are purely central forces?
- 2) n-n forces are same as n-p forces?
- 3) Quarks experiences all four fundamental forces of nature.
- 4) Baryons contains one quark and one anti-quark.
- 5) Electron capture is one of the modes of gamma decay process.
- 6) In radioactivity, after one half-life, mass of radioactive substance reduces to half.

Q.2 Answer the following.

- a) How ¹⁴C carbon dating is performed? Explain the step by step process in detail.
- **b)** Explain the working and basic principle of Proportional counter. Draw neat schematic figure to mention each component of the counter.
- c) Obtain the conditions for which, decay, decay, and electron capture process becomes energetically feasible.
- **d)** Draw the baryon decuplet, identify the particles in it along with their quark structures, charges and spins.

06

Q.3 Answer the following.

- a) Using the semi-empirical mass energy formula, Calculate the coulomb **08** coefficient and estimate the radius, for the mirror nuclei and [Given M() = 22.994124 u, M(=22.989768 u, neutron mass $m_n = 1.008665$ u, proton mass $m_p = 1.007825$ u, where $1 \text{ u} = 931.5 \text{ MeV/c}^2$, constants in semi-empirical formula: Volume term, Surface term, Coulomb term, asymmetry term, pairing term]
- b) Using semi-empirical mass formula, for given family of isobars, obtain the **08** relation for most stable nuclei.

Q.4 Answer the following.

- a) Explain the parity violation in beta-decay process and write in detail how
 10 it was experimentally shown.
- b) Find the Q-value and the threshold for the following nuclear reaction. [Given M() = 207.976641 u, M(=55.934939 u, M() = 209.984178 u, M(=53.939612 u, neutron mass $m_n = 1.008665$ u, proton mass $m_p=1.007825$ u, where 1 u = 931.5 MeV/c²]

Q.5 Answer the following.

- a) Explain meson theory of nuclear force. Using uncertainty principle and phenomenological arguments, obtain an expression for the Yukawa potential between nucleons.
 b) From Gamma ray selection rule classify the following multipole 08
- From Gamma ray selection rule classify the following multipole transitions.
 - i) $(1/2)^- \to (7/2)^-$
 - ii) $4^+ \rightarrow 2^+$
 - iii) $1^- \rightarrow 2^+$
 - iv) $(1/2)^- \rightarrow 3/2^+$

Q.6 Answer the following.

- a) Explain the alpha decay process in detail and get the expression for **10** Gamow's factor. Further, obtain the expression for decay probability involving Gamow's factor.
- b) Find out the classically forbidden regions in a potential of nuclei's 238-U
 and 228-U which emits alpha particles of 4.27 MeV and 6.81 MeV energies, respectively.

Q.7 Answer the following.

- a) Briefly explain what is the difference between cyclotron and synchrotron
 accelerators. Draw a neat schematic of synchrotron accelerator and explain the working and principle of each part.
- b) Classify nuclear reactions on the basis of projectile and ejectile particles **06** and explain them briefly.

110.						
	M.S	6c. (S	Semester - IV) (New) (CBCS) Examination: Oct/Nov - 2022 PHYSICS (APPLIED ELECTRONICS) Microwave Devices & Circuits			
-			ursday, 23-02-2023 Max. Marks: 7 1 To 06:00 PM	70		
Instr	uctio) All questions are compulsory. ?) Figure to right indicate full marks.			
Q.1	A)	Sele 1)	ect correct alternatives. The following waves do not exist in waveguides a) TM waves b) TE waves c) TEM waves d) TE and TM waves	06		
		2)	 Polarization of an EM wave is taken as the a) direction of the H-field b) normal to the direction of H-field c) direction of the E-field d) normal to the direction of E-field 			
		3)	 The two cavity Klystron is operated on the principle of a) velocity modulation b) current modulation c) velocity and current modulation d) none of the above 			
		4)	A microstripline is also called as a) open-strip line b) closed-strip line c) mismatch line d) none of the above			
		5)	The passive elements used to limit microwave power in a transmission line are called as a) isolators b) attenuators c) phase shifters d) none of the above			
		6)	Frequencies greater than 100 GHz cannot be used in conventional microwave tubes because of a) increase in the BW b) loading effect at input c) load resistance effect d) transit time effect			
	B)	Stat	te the following statements are true or false.	08		
	5,	1)	The solution of Maxwell's equations involves three space variables in addition to the time variable.	00		
	 The passive elements used to control the amount of microwave power in a transmission line are called as isolators. The quality factor Q, of a microstrip line is very high which may be required for high quality resonant MICS. 					
	 A line terminated in its characteristic impedance has a standing wave ratio of unity. 					
		5) 6)	A microstrip line is also called as open-strip line. In wave polarization, the orientation of electric field changes			

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SLR-GQ-16

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7)	The	imped	ance r	natching	is v	′ery d	lesirabl	le in	trans	smissio	n lines.

8) In a two-cavity klystron, the cavity close to the cathode is known as the buncher cavity.

Q.2	a)	 Answer the following (Any Four) 1) Explain the negative differential resistivity. 2) What is a TE wave? 3) What is meant by loading effect? 4) What is an isolator? 5) What is meant by linearly polarized wave? 	08
	b)	 Write notes on (Any Two) 1) Basic concepts two-wire line. 2) Types of microwave cavities. 3) Maxwell's field equations. 	06
Q.3	a)	 Answer the following (Any Two) 1) Discuss coaxial and stripline attenuators. 2) Discuss impedance matching. 3) Write a note on standing wave ratio. 	08
	b)	 Answer the following (Any One) 1) Explain the wave propagation in perfect insulators. 2) Discuss the various microwave tubes. 	06
Q.4	a)	 Answer the following (Any Two) 1) What are phase shifters? Explain. 2) Give a detailed account on striplines. 3) Derive equations for losses in coaxial lines. 	10
	b)	 Answer the following (Any One) 1) Discuss the planar transmission lines. 2) Write a note on modes in waveguides. 	04
Q.5	Ans a) b)	wer the following (Any Two) Derive equations for transmission and reflection coefficients. Describe the construction and working of a waveguide phase shifters.	14

c) Derive the TM mode field equations in a rectangular waveguide.

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M.Sc. (Semester - IV) (New) (CBCS) Examination: Oct/Nov - 2022 PHYSICS (APPLIED ELECTRONICS) Microcontrollers & Interfacing									
		ırsday, 23-0 To 06:00 Pl			Max. Marks	s: 80			
Instruc	2)	Attempt an	nd. 2 are compulsor y three questions fro ght indicate full mark	m Q. I	No. 3 to Q. No. 7				
Q.1 A) Fill i 1)	MOV TMO a) Cour	s by choosing corre D, #05H means nter 0 in Mode 1 er 1 in Mode 1	•	ernatives given below. Timer 1 in Mode – 2 Counter 1 in Mode 1	10			
	2)	After reset a) time c) time		est pric b) d)	ority interrupt. serial external interrupt 0				
	3)				mmunication TH1 register must L = 11.0592 MHz, SMOD = 1). E8 FD				
	4)	a) MO\	invalid instruction. / A,@R0 /C A, @ A+PC	b) d)	MOV A, @ DPTR MOV A,@R1				
	5)	a) Reso b) 8-bit c) Reso	of a 8 bit DAC can b plution of 1 part in 25 resolution plution of 0.39% of fu f the mentioned	5					
	6)	nu 4K bytes of a) 10 c) 12		requir b) d)	ed to select registers of internal 14 16				
	7)	a) Carr b) Carr c) Carr	l set for y from D6 to D7 but i y from D3 to D4 y out of D7 y from D6 to D7 and						
	8)	In mode-1, a) 00 c) 7F	the counter rolls ove	r whe b) d)	n counter goes uptoH. FF FFFF				
	9)	001. Find the a) Settl	out 000 is fed to a 3b he type of error? ing error	b)	C/ADC. The resultant output is Gain error				

Offset error Linearity error c) d)

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16

10) Subroutine ends with _____.

a)	IE	b)	RET
2		۲P	DET

c) RI, TI d) RETI

B) State whether the following statements are true or false.

- 1) There is no DEC DPTR instruction to match the INC DPTR.
- 2) ADC0804 converted output is 4-bit wide.
- 3) The LM35 requires no external calibration since it is inherently calibrated.
- 4) Internal data memory for 8051 is of 256 byte.
- 5) MOVC A, @A+DPTR access the data from the code memory.
- 6) After multiplication operation in 8051, if OV flag set then result is 16bit wide.

Q.2 Answer the following

- a) Explain following instructions.
 - 1)DJNZ radd2)DA A
- **b)** Draw and Explain Port-1 structure of 8051.
- c) Explain the general purpose register structure of 8051.
- d) Explain the function of the following pins of 8051.
 - 1) RESET 2) INTI

Q.3 Answer the following

- a) Draw and Explain the timer/counter logic circuit of 8051.
- b) Explain the serial communication modes of 8051.

Q.4 Answer the following

- a) Interface servo motor to 8051. Write a program to generate 50Hz PWM to control servo motor in angle between -90° to +90°.
- b) Design a PWM based DC motor speed control using microcontroller 8051.

Q.5 Answer the following

- a) Interface eight pushbutton to Port-2 and eight LEDs to Port-1. Write a program such that whenever the pushbutton is pressed its respective LED should glow.
- **b)** Write a program to generate a square wave of 8KHz on P2.2. Use Timer 1 for delay purpose. Assume crystal frequency is 11.0592 MHz.

Q.6 Answer the following

- a) Write a program with three subroutines to,
 - 1) transfer the following data from on-chip ROM to RAM locations starting at 30H.
 - 2) add them and save result in 70H and
 - find the average of the data and store it in R7. Notice that the data is stored in code space of on-chip ROM. ORG 250H
 - MYDATA: DB 3, 9, 6, 9, 7, 6, 4, 2, 8
- b) Explain how external interrupts are processed in 8051.

Q.7 Answer the following

- **a)** Draw the detailed interfacing diagram of 8051 microcontroller with DAC0808. Write program to generate triangular wave and square wave.
- b) Explain the auto reload mode of timer of 8051.